

5G Electronics: bridging the measurements challenges

M. Olszewska-Placha, M. Celuch QWED Sp. z o.o., Poland





Outline

- Modelling-based resonant material characterisation techniques for 5G and other emerging technologies.
- □ Broadband mm-wave characterisation of materials.
- □ iNEMI Project Tasks
- Advances in resonator-based characterisation techniques application to project tasks.
- Conclusions & outlook.



Modelling – based characterisation of materials for emerging technologies

Focus on resonant methods:

proven ultra-high acccuracy in GHz range

dedicated to low-loss & low-resitivity materials (both, bulk and thin sheets)

• ease-of-use

available on the market

repeatability & reproducibility for 5G under iNEMI project studies



Resonator methods – motivation and background (1)

Resonance in practice: given fixed strength of Signal(in), at resonance Signal (out) is strongest



Resonator methods – motivation and background (2)

Resonance in theory: non-zero electromagnetic fields (modes) exist in isolated structures (no excitation). Field properties are well-defined and linked to material properties. E.g. for cylindrical cavities:



Cylindrical resonator: single-mode versus multi-mode operation







- Resonators are multimode devices hence formally, material measurement can be performed at many frequencies in the same resonator.
 - Some modes provide highest accuracy of material characterization. Some are difficult to excite.
 - Software provided with the resonator in compatible only with modes preselected by the vendor.
 - Single mode resonators: SPDR, SCR
 - □ Multi-mode resonators: BCDR and FPOR.



Split-Post Dielectric Resonator (SPDR) - basics



metal enclosure dielectric resonator auxiliary dielectrics measured sample

For laminar dielectrics and high-resistivity semiconductors

resonant mode with EM fields mostly confined in and between those ceramic posts
 Field patterns remain practically unchanged but resonant frequencies and Q-factors change, providing information about SUT material parameters

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 Full 3D model of 10GHz SPDR
 Image: Comparison of the second s

Axisymmetrical 2D BOR model full EM information economies in computer effort : 10³ or more

SUT of $\varepsilon_s = \varepsilon_s' - j \varepsilon_s''$ is inserted into DR: resonant frequency changes from f_e to f_s and Q-factor changes from Q_e to Q_s .



Resonant Frequency (eps)

Data for dedicated software for material parameters extraction

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 QuickWave simulations of 2.5GHz SPDR performe in automatic Parameter Sweep for varying sample
 thickness (colours) and dielectric constant (eps)







Split-Post Dielectric Resonator (SPDR) – operation





For many practical materials, measuring only abs (S21) provides appropriate accuracy.

Device Packaging 2022 Keysight Option N1500A uses S21 (amplitude & phase) which helps enhance accuracy (*under study in iNEMI projection*).

Split Cylinder Resonator (SCR) – basics & operation





In-plane Electric field is applied to Sample



TE011 mode



High measurement precision

IPC-TM-650 2.5.5.13

Can be sensitive to many user errors

Typically interpolated to 5G mmWaves

Typically in-plane component of permittivity

Typical sample thicknesses around 100 um

Support temperature sweep measurement

https://www.keysight.com/us/en/assets/7018-

06384/brochures/5992-3438.pdf

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Operation workflow



Balanced-type circular disk resonator (BCDR) – basics & oper



INE

Close the resonator

Clamp and measure

Millimetre-wave characterisation of dielectric materials



Fabry-Perot Open resonator



• Single device

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- Spectrum: 20-110 GHz
- Frequency resolution: ca. 1.5 GHz
- Dk accuracy: $\Delta \epsilon / \epsilon < 0.5 \%$
- Df range: $10^{-5} < tan\delta < 10^{-2}$
- Sample diameter: > 3 inches
- Sample thickness: < 2 mm
- Fully automated measurement: (ca. 10 minutes in 20-50GHz) INEMI Session Device Packaging 2022

Bridging the gap between classical resonant methods and free space methods



Gaussian **TEM00q** modes



Electric field distribution - simulation model in QuickWave software



Fabry-Perot Open Resonator (FPOR) – measurement concept

@ multiple

frequencies



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Measurement:

Resonant frequency and Q factor

Electromagnetic model

simulation

Dielectric constant and loss tangent



Challenges for user

- mode identification
- mode tracking among plenty of other modes occurring in the FPOR

Solution

- Dedicated control software
- Automatic adaptive mode tracking algorithm
- No user intervention needed



Fabry-Perot Open Resonator (FPOR) – results





FPOR with a polystyrene (HIPS) sample placed on a sample holder

90 100 110

FEP 100um

- PVC 197um

HIPS_244um

PP 1079um

PC 799um

80

80

100



FPOR with OML frequency extenders operating in 75-110 GHz range. **INEMI**

5G/mmWave Materials Assessment and Characterization





Project Task3 Benchmarking popular measurement techniques on known material samples

- 3 material types
- 12 samples (6 in each of two sizes: 35x45mm, 90x90mm)

10 samples kits

11 labs





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5G/mmWave Materials Assessment and Characterization





*M. Celuch et al.N'Bridging the materials' permittivity traceability gap for 5G applications", IEEE Antennas & Propagation Symposium, 2021.

Repeatability and reproducibility studies







Project Task4



□ Industry samples provided by the members of Project Consortium

□ 2 types of material samples: electronic and automotive

□ Challenges in handling thin samples (e.g. fused silica)

Challenges in measuring thick automotive samples

Over 50 samples in total

5 labs

- □ 4 measurement techniques
- □ In the middle of the task completion





Fabry-Perot Open Resonator (FPOR) – in-plane anisotropy

With appropriately designed feeding loops, FPOR is capable of linear E-field polarization



BoPET (biaxially-oriented PET) involves thermal drawing in two in-plane directions with substantially different draw ratios, followed by crystallization. Hence, it is in-plane anisotropic.

For PETG (non-crystalline copolyesters, isotropic), resonant frequency does not depend on angular position of the sample.

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3.3 constant 3.2 3.1 Loss tangent Dielectric 2.9 20 30 40 50 30 20 40 Frequency (GHz) Frequency (GHz Device Packagi (a)

 $\times 10^{-3}$

T.Karpisz et al, "Measurement of in-plane anisotropy of dielectric materials with a Fabry-Perot open resonator", Proc. MIKON 2020



Task 4 additional activity: 2D imaging of material parameters



- 2D maps of electrical parameters: relative permittivity (Dk), loss tangent (Df), resistivity, or surface resistance
- □ Material homogeneity testing
- □ For qualitative and quantitative material testing
- □ Laminar dielectrics packaging in 5G systems
- Semiconductors industry high density packaging at a single wafer
- Battery cells materials uniformity of electrical parameters of anodes



2D imaging of material parameters – laminar dielectrics (1)



For low-loss dielectrics and high-resistivity semiconductors



- □ SPDR technique based 2D scanner
- □ Simulation model accounting for mechanical constraints,
 - e.g. dielectric membrane serving as sample holder
- □ 10GHz for higher spatial resolution



|S21| curves are for several scanning positions:

• curve max indicates resonant freq. (Dk) iNEMI Sessioncurve 3dB width indicates losses (Df) A joint product of QWED and Keysight, developed in the H2020 MMAMA project, has been acknowledged as Innovation Radar

of the European research.



 Waster Unit Control Application

 VNA

 VNA

 Q-Meter

 Motor X

 Results collection

Motor X 100Hs SPDR Votor XY scanner

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Fully automated

measurement procedure

through control application

2D imaging of material parameters – laminar dielectrics (2)

For low-loss dielectrics and high-resistivity semiconductors

2D surface map of dielectric constant of quartz







2D surface map of resistivity of semiconductor wafers





*courtesy L-IMP, Poland

2D surface map of measured Q-factor of "QWED" pattern made of organic semiconductor deposited on quartz





*courtesy MateriaNova, Belgium

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2D imaging of material parameters – conducting materials



2D map of resonant frequency (in GHz) of 2D SiPDR scanner

Semiconductor sample and its 2D resistivity map



Dedicated measurement control software





- ✓ Fully automated measurement procedure
- ✓ VNA/Q-Meter configuration, communication & control
- ✓ Built-in procedure for enhanced accuracy of Q-factor extraction
- ✓ Material parameters extraction
- Visualisation of measured material parameters values
- ✓ Import/export options



 Export of scan results to * csv and industrial *.gwy formats

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Ultra-Low Temperature Co-fired Ceramics for 6th Generation Electronic Packaging

ULTCC6G_EPac« M-ERA-NET Joint Project Ref CEA : X40955



Measurements of multilayer ULTCC substrates with SPDR and FPOR techniques

Measurements of bulk ULTCC composites



TE01delta cavity with a sample





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Simulations conducted with QuickWave EM software, developed & commercialised by QWED.

The original designs of QWED resonators for material measurements from Prof. Jerzy Krupka, e.g.:

J. Krupka, A. P. Gregory, O. C. Rochard, R. N. Clarke, B. Riddle, and J. Baker-Jarvis, "Uncertainty of complex permittivity measurements by split-post dielectric resonator technique", *J. Eur. Ceramic Soc.*, vol. 21, pp. 2673-2676, 2001.

J. Krupka and J. Mazierska, "Contactless measurements of resistivity of semiconductor wafers employing single-post and split-post dielectric-resonator techniques," *IEEE Trans. Instr. Meas.*, vol. 56, no. 5, pp. 1839-1844, Oct. 2007.



THANK YOU!





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